

**SEMICONDUCTOR  
TECHNICAL DATA**

**KTB2955**

TRIPLE DIFFUSED PNP TRANSISTOR

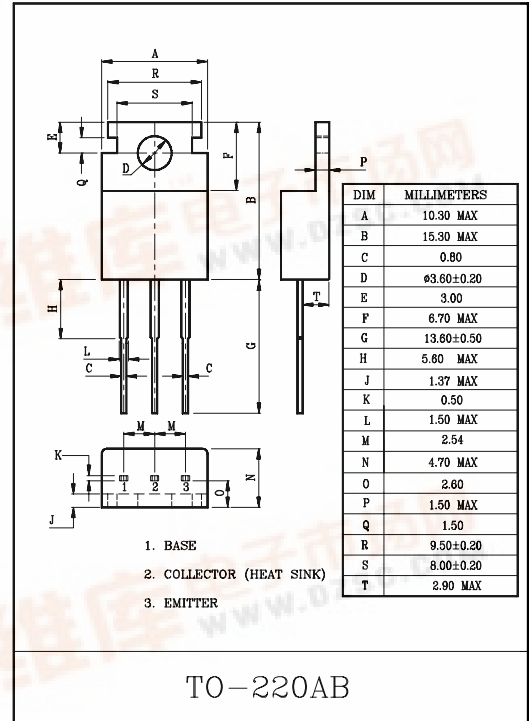
HIGH POWER AMPLIFIER APPLICATION.

FEATURES

- Complementary to KTD3055.
- Recommended for 30W~35W Audio Frequency Amplifier Output Stage.

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V <sub>CB0</sub>	-120	V
Collector-Emitter Voltage	V <sub>CE0</sub>	-120	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current	I <sub>C</sub>	-10	A
Base Current	I <sub>B</sub>	-1.0	A
Collector Power Dissipation (Tc=25°C)	P <sub>C</sub>	40	W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	-55~150	°C



ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> =-120V, I <sub>E</sub> =0	-	-	-10	μA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> =-5V, I <sub>C</sub> =0	-	-	-10	μA
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-50mA, I <sub>B</sub> =0	-120	-	-	V
DC Current Gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A	55	-	160	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-5A, I <sub>B</sub> =-0.5A	-	-	-2.5	V
Base-Emitter Voltage	V <sub>BE</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-5A	-	-	-1.5	V
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A	-	10	-	MHz
Collector Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, I <sub>E</sub> =0, f=1MHz	-	280	-	pF

Note : h<sub>FE</sub> Classification R:55~110 , O:80~160



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